Param Rathour - 190070049 Autumn Semester 2021-22

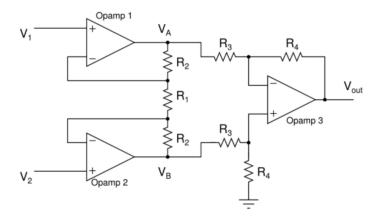


Figure 1: Three-Opamp Instrumentation Amplifier

1 Three-Opamp Instrumentation Amplifier using TL084

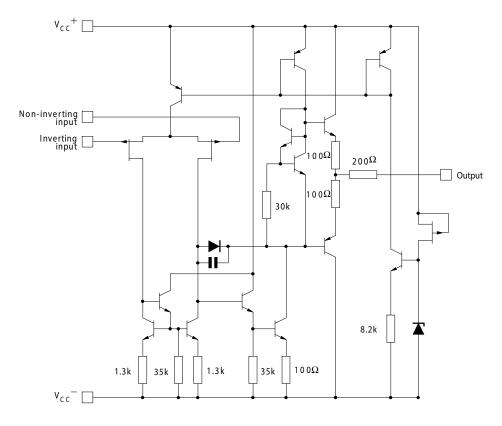


Figure 2: Circuit schematics TL084

$$A_{\rm d} = \frac{V_{\rm out}}{V_2 - V_1} = \frac{R_4}{R_3} \left(1 + \frac{2R_2}{R_1} \right)$$

1.1 Measurement of the Differential Voltage Gain, A_d

$$V_1 = 0, V_2 = 10\sin(\omega t)mV, V_{\rm CC} = 15V, -V_{\rm CC} = -15V, R_1 = R_2 = 10k\Omega, R_3 = 1k\Omega, R_4 = 100k\Omega$$

Here,
$$A_{\rm d} = \frac{R_4}{R_3} \left(1 + \frac{2R_2}{R_1} \right) = \frac{100k}{1k} \left(1 + \frac{2 \cdot 10k}{10k} \right) = 300$$

$$V_{\text{out}} = V_2 \cdot A_{\text{d}} = 10m \cdot 300 = 3V$$

2 INA 128 Instrumentation Amplifier

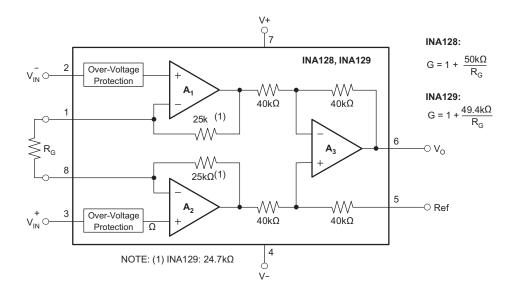


Figure 3: INA 128 Instrumentation Amplifier

$$A_{\rm d} = \frac{V_{\rm out}}{V_2 - V_1} = \frac{R_4}{R_3} \left(1 + \frac{2R_2}{R_1} \right) = \left(1 + \frac{50k}{R_G} \right)$$

2.1 Measurement of the Differential Voltage Gain, A_d

$$V_{\rm in-} = 0, V_{\rm in+} = 10\sin(\omega t)mV, V_{\rm CC} = 15V, -V_{\rm CC} = -15V, R_G = 180\Omega$$

Here,
$$A_{\rm d} = \left(1 + \frac{50k}{R_G}\right) = \left(1 + \frac{50k}{180}\right) = 277.\dot{7}$$

$$V_{\text{out}} = V_{\text{in+}} \cdot A_{\text{d}} = 10m \cdot 277.\dot{7} = 2.\dot{7}V$$

3 Questions

- i) In Sec 3.2 and 3.3, even under no-load conditions $V_{\rm out}$ was found to be non-zero. Give one or two reasons for this.
- \rightarrow Under no-load conditions, the four gauges are at rest and so ideally $R_g = R_1 = R_2 = R_3 = R_4$, but due to tolerances of resistors this is not achieved and a small voltage difference is present which gets amplified by the op-amp.
- \rightarrow Op-amp non idealities like input bias current, offset voltage also contribute to non-zero $V_{\rm out}$.
- ii) Give two or three major advantages of the three-Opamp instrumentation amplifier as compared to the single-Opamp difference amplifier of Experiment 6.
- $\rightarrow A_{\rm d}$ is easily changeable and can be set to higher values.
- \rightarrow Higher differential input resistance.
- \rightarrow High CMRR (due to high $A_{\rm d}$ and low $A_{\rm cm}$).
- iii) Look at the data sheets of TL084 and INA128. Identify the major differences between these two ICs i.e. Opamp parameters crucial for difference amplifier applications, such as the Loadcell application discussed in this experiment
- \rightarrow INA128 has a higher CMRR (120dB) than TL084 (86dB)
- \rightarrow TL084 has a lower input bias current (20pA) than INA128 (5nA)
- \rightarrow INA128 has a lower offset voltage (50 μV) than TL084 (3mV)
- \rightarrow TL084 has a higher slew rate $(16V/\mu s)$ than INA128 $(4V/\mu s)$
- \rightarrow INA128 has a lower drift $(0.5\mu V/C^{\circ})$ than TL084 $(10\mu V/C^{\circ})$
- iv) Identify one or two parameters of the INA128 that makes it superior to the TL084 based instrumentation amplifier.
- \rightarrow INA128 is superior to TL084 in CMRR, offset voltage and drift
- \rightarrow Additionally, INA128 has higher input voltage protection (40V) and lower noise (7 vs $15nV/\sqrt{\text{Hz}}$)

3.1 Learnings

Learnt the applications of instrumentation amplifiers, strain gages.